

High voltage fast-switching NPN power transistor

Features

- High voltage capability
- Low spread of dynamic parameters
- Very high switching speed
- Integrated antiparallel collector-emitter diode

Application

- Electronic ballast for fluorescent lighting

Description

The device is manufactured using high voltage multi-epitaxial planar technology for high switching speeds and high voltage capability.

It uses a cellular emitter structure with planar edge termination to enhance switching speeds while maintaining the wide RBSOA.

The STL series is designed for use in compact fluorescent lamps.

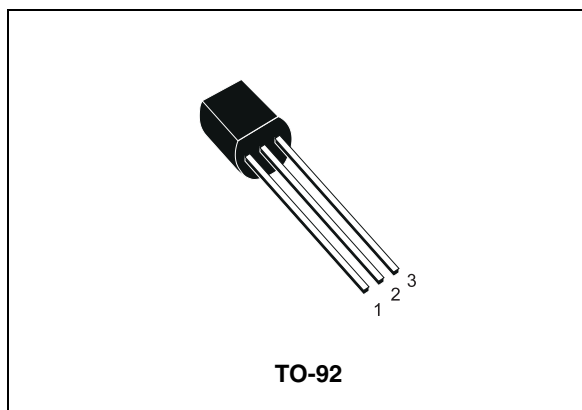


Figure 1. Internal schematic diagram

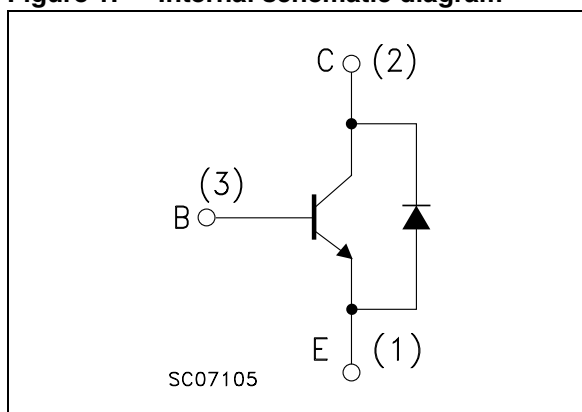


Table 1. Device summary

| Order codes | Marking ⁽¹⁾ | Package | Packaging |
|-------------|------------------------|---------|-----------|
| STL73D | L73DL | TO-92 | Bag |
| | L73DH | | |
| STL73D-AP | L73DL | TO-92 | Ammopack |
| | L73DH | | |

1. The product is classified in DC current gain group L and group H, see [Table 5: hFE classification](#). STMicroelectronics reserves the right to ship from any group according to production availability.

1 Electrical ratings

Table 2. Absolute maximum ratings

| Symbol | Parameter | Value | Unit |
|-----------|--|---------------|------|
| V_{CES} | Collector-emitter voltage ($V_{BE} = 0$) | 700 | V |
| V_{CEO} | Collector-emitter voltage ($I_B = 0$) | 400 | V |
| V_{EBO} | Emitter-base voltage ($I_C = 0$, $I_B = 0.5$ A, $t_P < 10$ μ s) | $V_{(BR)EBO}$ | V |
| I_C | Collector current | 1.5 | A |
| I_{CM} | Collector peak current ($t_P < 5$ ms) | 3 | A |
| I_B | Base current | 0.5 | A |
| I_{BM} | Base peak current ($t_P < 5$ ms) | 1.5 | A |
| P_{TOT} | Total dissipation at $T_C = 25$ °C | 1.5 | W |
| T_{STG} | Storage temperature | -65 to 150 | °C |
| T_J | Max. operating junction temperature | 150 | °C |

Table 3. Thermal data

| Symbol | Parameter | Value | Unit |
|------------|---|-------|------|
| R_{thJC} | Thermal resistance junction-case max | 83 | °C/W |

2 Electrical characteristics

$T_{\text{case}} = 25\text{ °C}$ unless otherwise specified.

Table 4. Electrical characteristics

| Symbol | Parameter | Test conditions | Min. | Typ. | Max. | Unit |
|--|---|---|---------|---------------------|-----------------|---|
| I_{CEV} | Collector cut-off current ($V_{\text{BE}} = -1.5\text{ V}$) | $V_{\text{CE}} = 700\text{ V}$ $V_{\text{CE}} = 700\text{ V}$ $T_{\text{C}} = 125\text{ °C}$ | | | 1 5 | mA mA |
| $V_{(\text{BR})\text{EBO}}$ | Emitter-base breakdown voltage ($I_{\text{C}} = 0$) | $I_{\text{E}} = 10\text{ mA}$ | 9 | | 18 | V |
| $V_{\text{CEO(sus)}}^{(1)}$ | Collector-emitter sustaining voltage ($I_{\text{B}} = 0$) | $I_{\text{C}} = 10\text{ mA}$ | 400 | | | V |
| $V_{\text{CE(sat)}}^{(1)}$ | Collector-emitter saturation voltage | $I_{\text{C}} = 0.3\text{ A}$ $I_{\text{B}} = 60\text{ mA}$ $I_{\text{C}} = 0.6\text{ A}$ $I_{\text{B}} = 120\text{ mA}$ $I_{\text{C}} = 1\text{ A}$ $I_{\text{B}} = 250\text{ mA}$ | | 0.15 0.25 0.4 | 0.4 0.6 1 | V V V |
| $V_{\text{BE(sat)}}^{(1)}$ | Base-emitter saturation voltage | $I_{\text{C}} = 0.6\text{ A}$ $I_{\text{B}} = 120\text{ mA}$ | | 0.95 | 1.1 | V |
| h_{FE} | DC current gain | $I_{\text{C}} = 0.6\text{ A}$ $V_{\text{CE}} = 3\text{ V}$ $I_{\text{C}} = 1.2\text{ A}$ $V_{\text{CE}} = 5\text{ V}$ | 10 4 | | 21 10 | |
| t_{r} t_{s} t_{f} | Resistive load Rise time Storage time Fall time | $V_{\text{CC}} = 125\text{ V}$ $I_{\text{C}} = 1\text{ A}$ $I_{\text{B(on)}} = -I_{\text{B(off)}} = 200\text{ mA}$ $T_{\text{P}} = 25\text{ }\mu\text{s}$ | | | 1 4 0.7 | μs μs μs |
| t_{s} | Inductive load Storage time | $I_{\text{C}} = 0.3\text{ A}$ $V_{\text{Clamp}} = 300\text{ V}$ $I_{\text{B(on)}} = -I_{\text{B(off)}} = 60\text{ mA}$ $L = 3\text{ mH}$ | | 0.3 | | μs |
| V_{F} | Diode forward voltage | $I_{\text{F}} = 0.5\text{ A}$ | | | 1.5 | V |

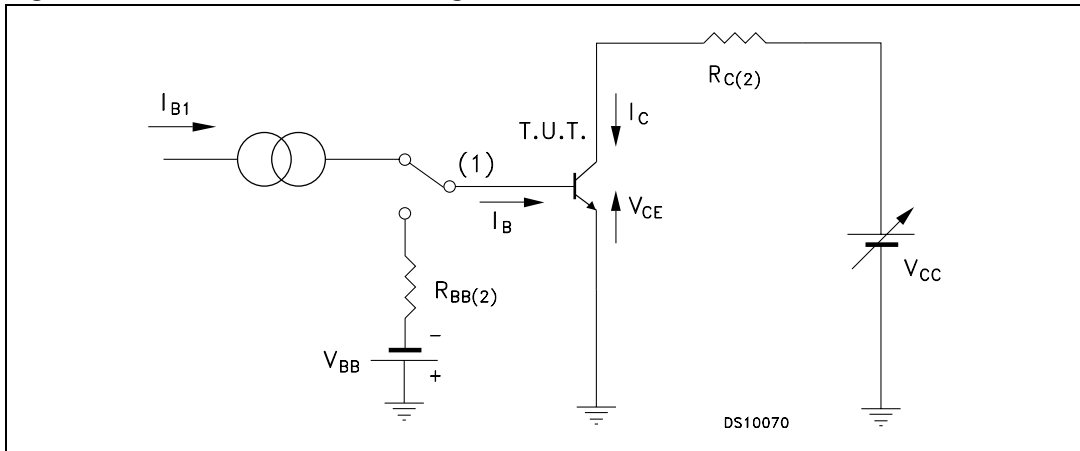
1. Pulse test: pulse duration $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$

Table 5. h_{FE} classification

| Symbol | Parameter | Group | Value | | |
|-----------------|---|-------|-------|------|------|
| | | | Min. | Max. | Unit |
| h_{FE} | DC current gain $V_{\text{CE}} = 3\text{ V}$, $I_{\text{C}} = 0.6\text{ A}$ | L | 10 | 16 | |
| | | H | 15 | 21 | |

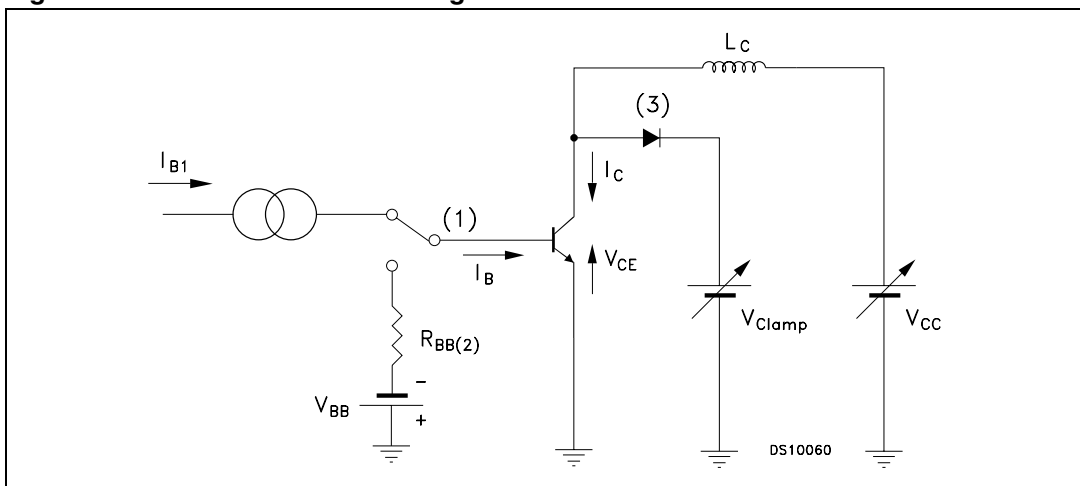
2.1 Test circuits

Figure 2. Resistive load switching test circuit



1. Fast electronic switch
2. Non-inductive resistor

Figure 3. Inductive load switching test circuit



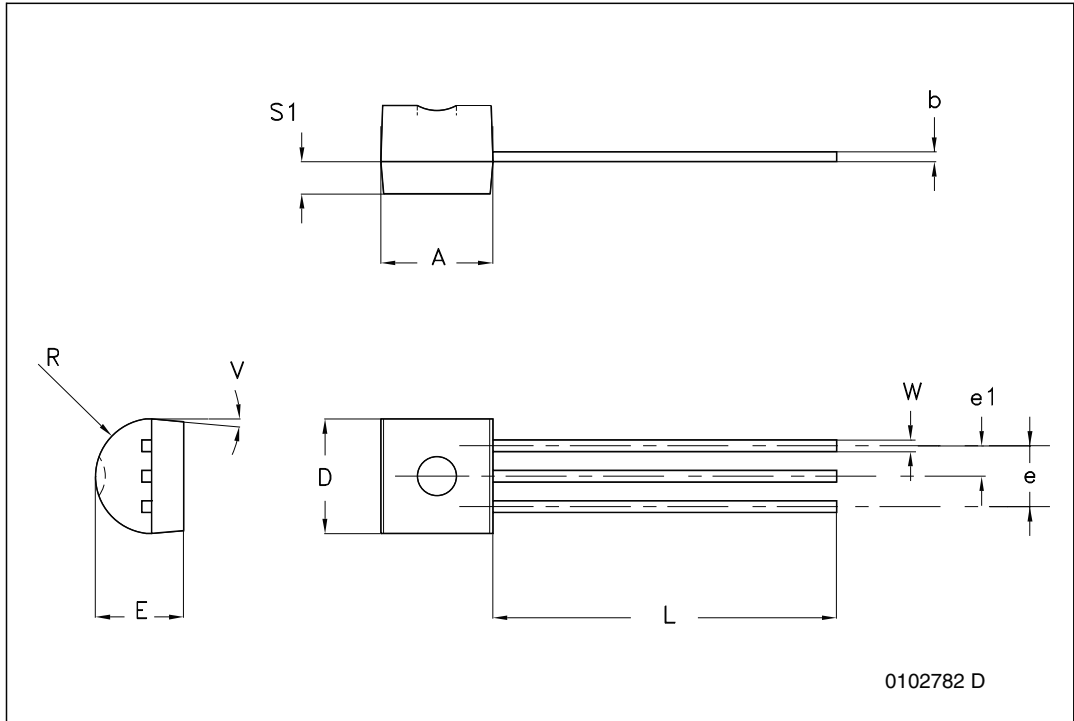
1. Fast electronic switch
2. Non-inductive resistor
3. Fast recovery rectifier

3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

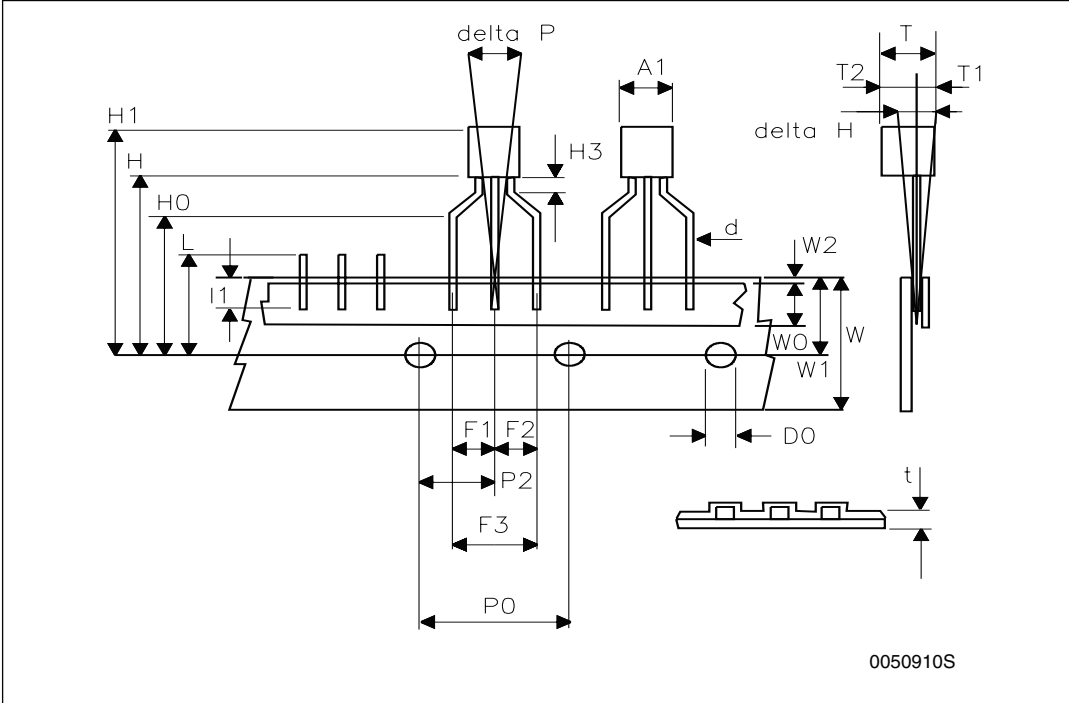
TO-92 bulk shipment mechanical data

| Dim. | mm. | | |
|------|-------|------|-------|
| | Min. | Typ. | Max. |
| A | 4.32 | | 4.95 |
| b | 0.36 | | 0.51 |
| D | 4.45 | | 4.95 |
| E | 3.30 | | 3.94 |
| e | 2.41 | | 2.67 |
| e1 | 1.14 | | 1.40 |
| L | 12.70 | | 15.49 |
| R | 2.16 | | 2.41 |
| S1 | 0.92 | | 1.52 |
| W | 0.41 | | 0.56 |
| V | | 5° | |



TO-92 ammpack shipment (suffix"-AP") mechanical data

| Dim. | mm. | | |
|---------|-------|-------|-------|
| | Min. | Typ. | Max. |
| A1 | | | 4.80 |
| T | | | 3.80 |
| T1 | | | 1.60 |
| T2 | | | 2.30 |
| d | | | 0.48 |
| P0 | 12.50 | 12.70 | 12.90 |
| P2 | 5.65 | 6.35 | 7.05 |
| F1,F2 | 2.44 | 2.54 | 2.94 |
| F3 | 4.98 | 5.08 | 5.48 |
| delta H | -2.00 | | 2.00 |
| W | 17.50 | 18.00 | 19.00 |
| W0 | 5.70 | 6.00 | 6.30 |
| W1 | 8.50 | 9.00 | 9.25 |
| W2 | | | 0.50 |
| H | 18.50 | | 20.50 |
| H3 | 0.5 | 1 | 1.5 |
| H0 | 15.50 | 16.00 | 16.50 |
| H1 | | | 25.00 |
| D0 | 3.80 | 4.00 | 4.20 |
| t | | | 0.90 |
| L | | | 11.00 |
| I1 | 3.00 | | |
| delta P | -1.00 | | 1.00 |



4 Revision history

Table 6. Document revision history

| Date | Revision | Changes |
|-------------|----------|--|
| 12-Nov-2008 | 1 | Initial release. |
| 25-Nov-2009 | 2 | Added order code STL73D-AP Table 1 on page 1 . |

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